## **SMD Small Signal Schottky Diodes**



# **CDBH0230-G**

Reverse Voltage: 30 Volts Forward Current: 200 mA

**RoHS Device** 

#### **Features**

- -Extremely fast switching speed.
- -Small surface mount type.
- -Low reverse current and low forward voltage.

#### Mechanical data

-Case: SOD-523 standard package, Molded Plastic

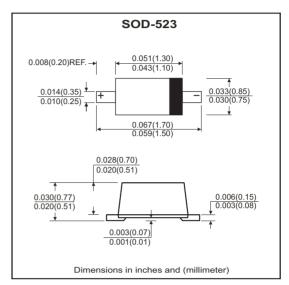
-Terminals: Solderable per MIL-STD-750, method 2026

-Marking code: cathode band & JV

-Mounting position: Any

-Weight: 0.012 gram(approx.)





#### Maximum Ratings (at TA=25°C unless otherwise noted)

Parameter	Symbol	CDBH0230-G	Unit
Non-repetitive peak reverse voltage	Vrm	30	V
RMS voltage	V <sub>RMS</sub>	21	V
DC blocking voltage	VDC	30	V
Average rectified output current	lo	100	mA
Forward continuous current	lF	200	mA
Repetitive peak forward current	IFRM	300	mA
Forward surge current	IFSM	600	mA
Power dissipation	Po	200	mW
Thermal resistance junction to ambient air	Reja	625	°C/W
Junction temperature	TJ	125	°C
Storage temperature range	Тѕтс	-65 ~ <b>+</b> 150	°C

## Electrical Characteristics (at TA=25°C unless otherwise noted)

Parameter	Symbol	Conditions	Min.	Тур.	Max.	Unit
Reverse Breakdown voltage	V <sub>(BR)R</sub>	I <sub>R</sub> =100μA	30			V
	V <sub>F1</sub>	I⊧=0.1mA			240	mV
	V <sub>F2</sub>	I <sub>F</sub> =1.0mA			320	mV
Forward voltage	V <sub>F3</sub>	I <sub>F</sub> =10mA			400	mV
	VF4	I=30mA			500	mV
	V <sub>F5</sub>	I=100mA			1000	mV
Reverse current	lr	V <sub>R</sub> =25V			2.0	μA
Capacitance between terminals	Ст	V <sub>R</sub> =1V, f=1.0MHz			10	pF
Reverse recovery time	trr	I <sub>F</sub> =10mA, I <sub>R</sub> =10mA to 1mA R <sub>L</sub> =100 $\Omega$			5.0	nS

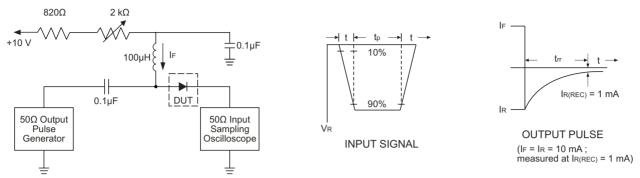
REV:A

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### Rating and Characteristic Curves (CDBH0230-G)

Fig.1- Recovery Time Equivalent Test Circuit



Notes:

- 1. A 2.0 kΩ variable resistor adjusted for a Forward Current (IF) of 10 mA.
- 2. Input pulse is adjusted so IR(peak) is equal to 10 mA.
- 3. tp >> tıT

Fig.2 - Typical Forward Characteristics

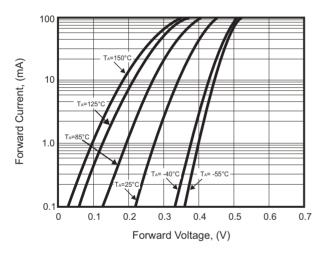


Fig.3 - Leakage Current

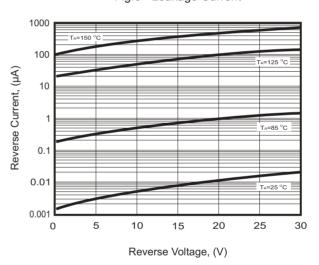
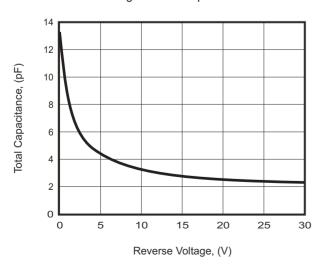


Fig.4 - Total Capacitance

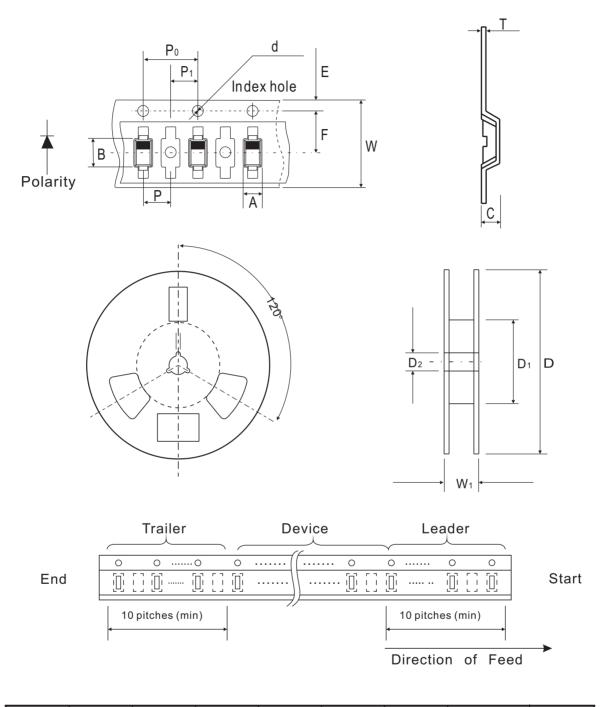


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# **Reel Taping Specification**



	SYMBOL	Α	В	С	d	D	<b>D</b> 1	D2
SOD-523	(mm)	0.90 ± 0.10	1.94 ± 0.10	0.73 ± 0.10	1.50 + 0.10	178 ± 1.00	54.40 ± 0.40	13.00 ± 0.20
	(inch)	0.035 ± 0.004	0.076 ± 0.004	0.029 ± 0.004	0.059 + 0.004	7.008 ± 0.039	2.142 ± 0.016	0.512 ± 0.008

	SYMBOL	Е	F	Р	P0	P1	W	<b>W</b> 1
SOD-523	(mm)	1.75 ± 0.10	3.50 ± 0.05	2.00 ± 0.10	4.00 ± 0.10	2.00 ± 0.10	8.00 + 0.30 / - 0.10	9.50 ± 1.00
	(inch)	0.069 ± 0.004	0.138 ± 0.002	0.079 ± 0.004	0.158 ± 0.004	0.079 ± 0.004	0.315 + 0.012 / - 0.004	0.374 ± 0.039



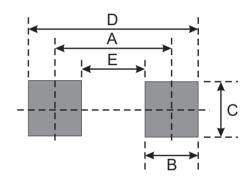
# **Marking Code**

Part Number	Marking Code
CDBH0230-G	JV



# **Suggested PAD Layout**

6175	SOD-523				
SIZE	(mm)	(inch)			
Α	1.40	0.055			
В	0.60	0.024			
С	0.70	0.028			
D	2.00	0.079			
E	0.80	0.031			



# **Standard Packaging**

	REEL PACK				
Case Type	REEL ( pcs )	Reel Size (inch)			
SOD-523	3,000	7			

# **Mouser Electronics**

**Authorized Distributor** 

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